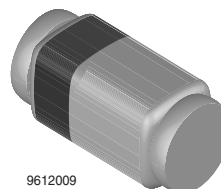


Small Signal Switching Diodes, Low Leakage Current

Features

- Silicon Planar Diodes
- Very low reverse current
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



9612009

Applications

Protection circuits, time delay circuits, peak follower circuits, logarithmic amplifiers

Mechanical Data

Case: QuadroMELF Glass case (SOD-80)

Weight: approx. 34 mg

Cathode Band Color: Black

Packaging Codes/Options:

GS18 / 10 k per 13" reel (8 mm tape), 10 k/box

GS08 / 2.5 k per 7" reel (8 mm tape), 12.5 k/box

Parts Table

Part	Type differentiation	Ordering code	Remarks
BAQ133	$V_{RRM} = 40\text{ V}$	BAQ133-GS18 or BAQ133-GS08	Tape and Reel
BAQ134	$V_{RRM} = 70\text{ V}$	BAQ134-GS18 or BAQ134-GS08	Tape and Reel
BAQ135	$V_{RRM} = 140\text{ V}$	BAQ135-GS18 or BAQ135-GS08	Tape and Reel

Absolute Maximum Ratings

$T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified

Parameter	Test condition	Part	Symbol	Value	Unit
Reverse voltage		BAQ133	V_R	30	V
		BAQ134	V_R	60	V
		BAQ135	V_R	125	V
Peak forward surge current	$t_p = 1\text{ }\mu\text{s}$		I_{FSM}	2	A
Forward current			I_F	200	mA

Thermal Characteristics

$T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Thermal resistance junction to ambient air	on PC board 50 mm x 50 mm x 1.6 mm	R_{thJA}	500	K/W
Junction temperature		T_j	175	$^{\circ}\text{C}$
Storage temperature range		T_{stg}	- 65 to + 175	$^{\circ}\text{C}$

Electrical Characteristics

$T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified

Parameter	Test condition	Part	Symbol	Min	Typ.	Max	Unit
Forward voltage	$I_F = 100\text{ mA}$		V_F			1	V
Reverse current	$E \leq 300\text{ lx}$, rated V_R		I_R		1	3	nA
	$E \leq 300\text{ lx}$, rated V_R , $T_J = 125\text{ }^{\circ}\text{C}$		I_R			0.5	μA
	$E \leq 300\text{ lx}$, $V_R = 15\text{ V}$	BAQ133	I_R		0.5	1	nA
	$E \leq 300\text{ lx}$, $V_R = 30\text{ V}$	BAQ134	I_R		0.5	1	nA
	$E \leq 300\text{ lx}$, $V_R = 60\text{ V}$	BAQ135	I_R		0.5	1	nA
Breakdown voltage	$I_R = 5\text{ }\mu\text{A}$, $t_p/T = 0.01$, $t_p = 0.3\text{ ms}$	BAQ133	$V_{(BR)}$	40			V
		BAQ134	$V_{(BR)}$	70			V
		BAQ135	$V_{(BR)}$	140			V
Diode capacitance	$V_R = 0$, $f = 1\text{ MHz}$		C_D			3	pF

Typical Characteristics ($T_{amb} = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)

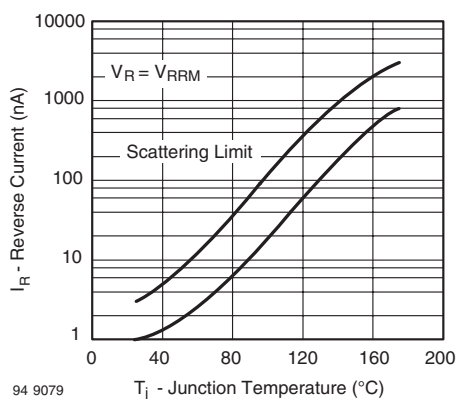


Figure 1. Reverse Current vs. Junction Temperature

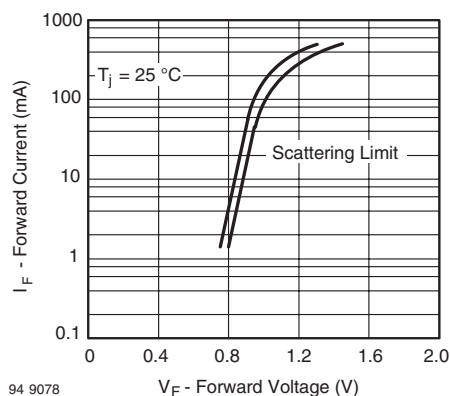
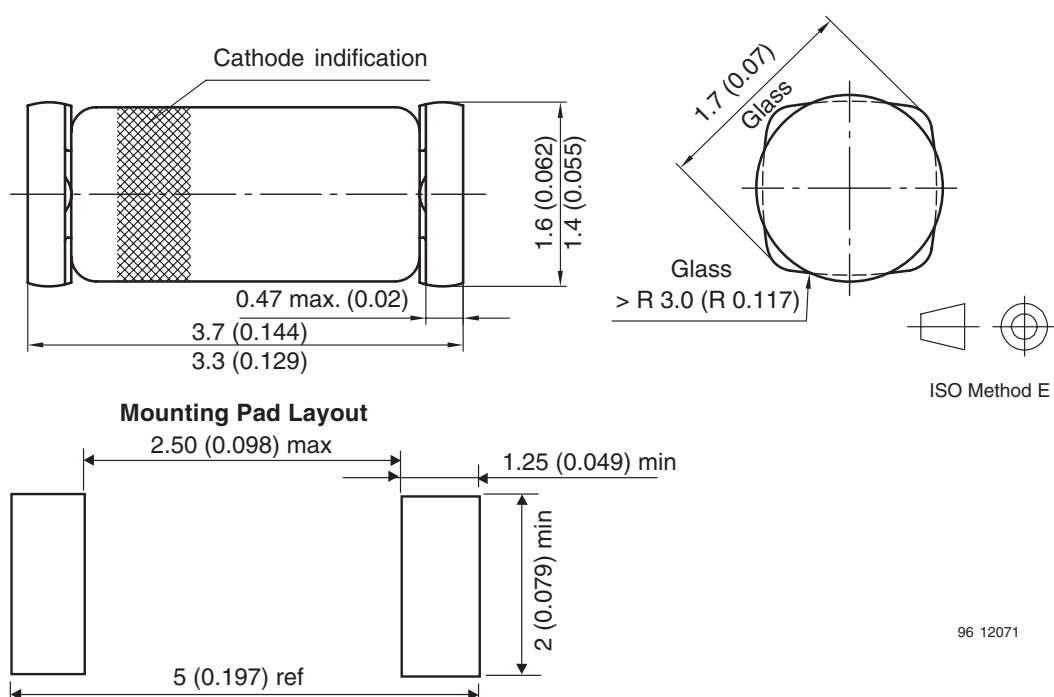


Figure 2. Forward Current vs. Forward Voltage

Package Dimensions in mm (Inches)



96 12071

Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design
and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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